TAPERED LASER

GaAs Semiconductor Laser Diode



PRELIMINARY SPECIFICATION

General Product Information

Tapered Laser

EYP-TPL-0808-01000-3006-CMT03-0000

Product	Application
808 nm Tapered Laser	Spectroscopy
C-Mount Package	Metrology

Absolute Maximum Ratings

	Symbol	Unit	min	typ	max
Storage Temperature	Τ _s	°C	-40		85
Operational Temperature at Case	T _C	°C	0		50
Current	I _F	А			2.8
Reverse Voltage	V _R	V			0
Output Power	P _{opt}	W			1.1

Recommended Operational Conditions

	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	0		40
Forward Current	١ _F	А			2.5
Output Power	P _{opt}	W			1.0

Characteristics at T_{amb} 25 °C at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	803	808	813
Spectral Width (FWHM)	Δλ	nm		2	4
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.3	
Output Power @ $I_F = 2.5 A$	P _{opt}	W	1.0		
Slope Efficiency	η	W / A	0.8	0.9	
Threshold Current	I _{th}	А	0.4	0.6	0.8
Operational Current @ $P_{opt} = 1 W$	I _F	А			2.5
Cavity Length	L	μm		2750	
Cavity Length	L	μm		2750	



non condensing

non condensing

Stress in excess of the Absolute Maximum Ratings can cause permanent damage to the device. Operation at the Absolute Maximum Rating for extended periods of time can adversely affect the device realibility and may lead to reduced operational life.

non condensing		

Measurement Conditions / Comments
see images on page 4

see images on page 4

total output measured with integrating sphere

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Characteristics at T_{amb} 25 °C at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Output Aperture (at front side)	d _{output}	μm		190	
Astigmatism	А	μm		500	750
Divergence parallel (FWHM)	$\Theta_{ }$	0	12	15	18
Divergence perpendicular (FWHM)	Θ_{\perp}	0		28	
Polarization				TE	

Measurement Conditions / Comments			
E field parallel to junction plane			

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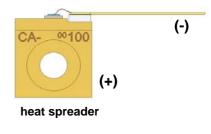
EYP-TPL-0808-01000-3006-CMT03-0000

SymbolUnitmintypmaxEmission PlaneImm7.057.207.35C-Mount Thicknessdmm2.75	Package Dimensions					
		Symbol	Unit	min	typ	max
C-Mount Thickness d mm 2.75	Emission Plane		mm	7.05	7.20	7.35
	C-Mount Thickness	d	mm		2.75	

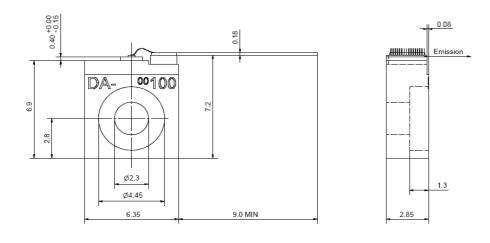
Package Pinout

Cathode (-)	Mounting Wire	
Cathode (-) Anode (+)	Housing	

mounting wire



Package Drawings



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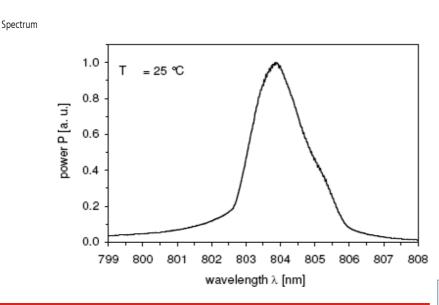
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Typical Measurement Results



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The TPL diode type is known to be sensitive against thermal stress. Operating at moderate temperatures on propper heat sinks will contribute to a long lifetime of the diode.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase thread to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.







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